TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG50J201HC

High Power Switching Applications

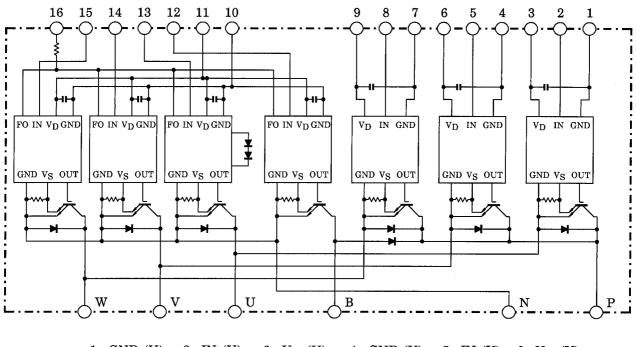
Motor Control Applications

- Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : V_{CE} (sat) = 2.8 V (Max.)

toff = 3.0 μs (Max.)

- t_{rr} = 0.30 μs (Max.)
- Outline : TOSHIBA 2-110A1A
- Weight : 520 g

Equivalent Circuit



1. GND (U)	2. IN (U)	3. VD (U)	4. GND (V)	5. IN (V)	6. V _D (V)
7. GND (W)	8. IN (W)	9. $V_{\mathbf{D}}^{-}(\mathbf{W})$	10.GND (L)	11.VD (L)	12.IN (B)
13.IN (X)	14.IN (Y)	$15.\mathrm{IN}$ (Z)	16.FO	_	

Maximum Ratings (T_j = 25°C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
	Supply voltage	P-N power terminal	V _{CC}	450	V
	Collector-emitter voltage	_	V _{CES}	600	V
Inverter	Collector current	Tc = 25°C, DC	Ι _C	50	А
Inverter	Forward current	Tc = 25°C, DC	lF	50	А
	Collector power dissipation	Tc = 25°C	P _C	150	W
	Junction temperature	_	Tj	150	°C
	Supply voltage	P-N power terminal	V _{CC}	450	V
Brake	Collector-emitter voltage	_	V _{CES}	600	V
	Collector current	Tc = 25°C, DC	Ι _C	30	А
	Reverse voltage	_	V _R	600	V
	Forward current	Tc = 25°C, DC	lF	30	А
	Collector power dissipation	Tc = 25°C	P _C	80	W
	Junction temperature	_	Tj	150	°C
	Control supply voltage	V _D -GND terminal	VD	20	V
Control	Input voltage	IN-GND terminal	V _{IN}	20	V
Control	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	14	mA
Module	Operating temperature	_	TC	-20 ~ +100	°C
	Storage temperature range	_	T _{stg}	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M5	_	3	N∙m

Electrical Characteristics (T_j = 25° C)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	losy	V _{CE} = 600V	T _j = 25°C	_	_	1	mA
	ICEX		T _j = 125°C	_	—	20	
Collector-emitter	Varia	$\begin{array}{l} V_{D} = 15 \; V, \; I_{C} = 50 \; A \\ V_{IN} = 15 \; V \rightarrow 0 \; V \end{array}$	T _j = 25°C	_	2.3	2.8	v
saturation voltage	V _{CE (sat)}		T _j = 125°C	_	2.3	_	
Forward voltage	V _F	I _F = 50A		_	2.1	3.0	V
	t _{on}			_	0.8	2.0	
Switching time	t _{off}	$V_{CC} = 300 \text{ V}, \text{ I}_{C} = 50 \text{ A}$ $V_{D} = 15 \text{ V}, \text{ V}_{IN} = 15 \text{ V}$	`↔ 0 V	_	1.2	3.0	110
	t _f	Inductive load (Note 1)		_	0.25	0.5	μs
	t _{rr}				0.1	0.3	

b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	losy	V _{CF} = 600V	T _j = 25°C	_	_	1	mA
	ICEX	VCE - 000V	T _j = 125°C	_	_	20	mA
Collector-emitter		V _D = 15 V, I _C = 30 A	T _j = 25°C	_	1.7	2.7	V
saturation voltage	V _{CE (sat)}	$1/\dots = 4E 1/\dots = 0 1/$	T _j = 125°C	_	1.6	_	v
	I _R	V _R = 600 V	T _j = 25°C	_	—	1	mA
Reverse current			T _j = 125°C	_	—	20	ША
Forward voltage	VF	I _F = 30A		_	2.0	2.5	V
	t _{on}	V_{CC} = 300 V, I _C = 30 A V _D = 15 V, V _{IN} = 15 V ↔ 0 V		_	0.9	2.0	
Switching time	t _{off}			_	1.7	3.0	
	t _f	Inductive load	(Note 1)	_	0.25	0.5	μs
	t _{rr}			_	0.15	0.3	

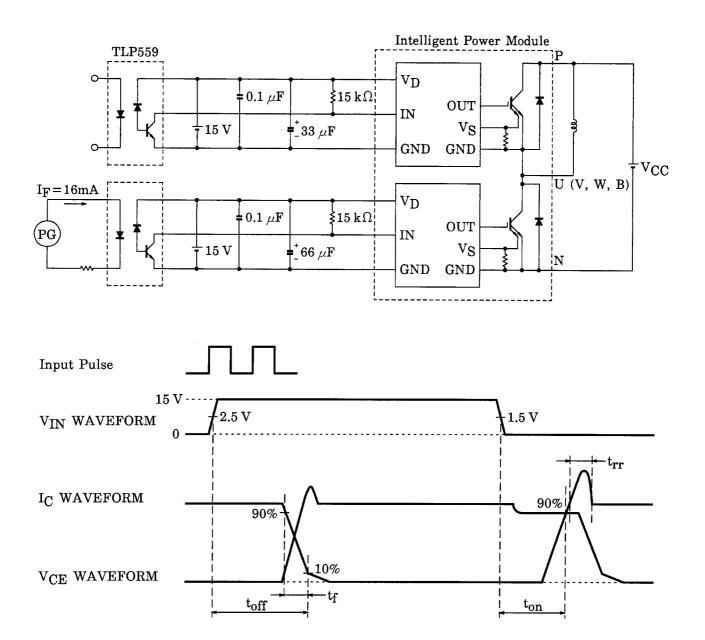
c. Control Stage ($T_j = 25^{\circ}C$)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I _{D (H)}	– V _D = 15 V	_	8	—	m۸
	Low side	I _{D (L)}			35	_	mA
Input-on signal voltage	e		V _D = 15 V, I _C = 50 mA	1.3	1.5	1.7	V
Input-off signal voltage	e		V _D = 15 V, I _C = 50 mA	2.2	2.5	2.8	V
Fault output	Protection	I _{FO (on)}	- V _D = 15 V	8	10	12	
current	Normal	I _{FO (off)}	VD = 13 V	_	_	1	mA
Over current	Inverter		V _D = 15 V, T _j = 125°C	75	100	_	A
protection trip level	Brake	OC		40	_	_	
Short circuit	Inverter		V _D = 15 V, T _j = 125°C	110	150	—	A
protection trip level	Brake	SC		60	_	_	
Over current cut-off tir	ne	t _{off (OC)}	V _D = 15 V		5	—	μs
Over	Trip level	OT	Case temperature 110	110	118	125	
temperature protection	Reset level	OTr		_	80	_	°C
Control supply under voltage protection	Trip level	UV		11.0	12.0	12.5	
	Reset level	UVr		_	12.5	_	V
Fault output pulse width		t _{FO}	V _D = 15 V	1	2	3	ms

d. Thermal Resistance (T_j = 25°C)

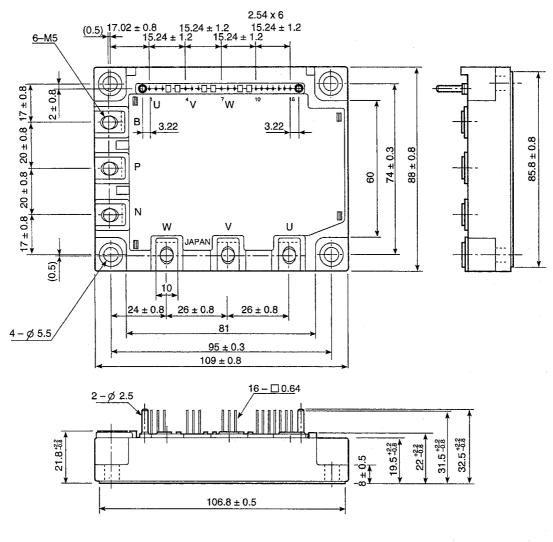
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	R _{th (j-c)}	Inverter IGBT stage	-	_	0.833	°C / W
Junction to case thermal		Inverter FRD stage		_	2.000	
resistance		Brake IGBT stage	_	-	1.562	
		Brake FRD stage		_	2.000	
Case to fin thermal resistance	R _{th (c-f)}	Compound is applied		0.05	-	°C/W

Note 1: Switching time test circuit & timing chart



Package Dimensions: TOSHIBA 2-110A1A

Unit: mm



GND IN VD GNDIN VD GND IN VD GND VD IN IN IN FO (U) (V) (W) (B) (X) (Y) (Z) 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 Signal Terminal 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0

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